



An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

## **NPN SILICON PLANAR TRANSISTORS**



BC171 , A, B BC172, A, B, C BC174, A, B

TO-92 Plastic Package

# **Amplifier Transistors**

# ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	BC174	BC171	BC172	UNIT
Collector Emitter Voltage	$V_{CEO}$	65	45	25	V
Collector Base Voltage	$V_{CBO}$	80	50	30	V
Emitter Base Voltage	$V_{EBO}$		V		
Collector Current Continuous	I <sub>C</sub>		mA		
Total Device Dissipation @ Ta=25°C	$P_{D}$	350			mW
Derate Above 25°C		2.8			mW/ºC
Total Device Dissipation @ Tc=25°C	$P_{D}$	1.0			W
Derate Above 25°C		8.0			mW/ºC
Operating And Storage Junction Temperature Range	$T_j$ , $T_{stg}$	-55 to +150			∘C

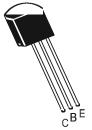
#### THERMAL RESISTANCE

Junction to ambient	$R_{th(j-a)}$	357	ºC/W
Junction to case	$R_{th(j-c)}$	125	ºC/W

# ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION		UNIT		
			MIN	TYP	MAX	UNII
Collector Emitter Breakdown	$BV_{CEO}$	$I_C=2mA,I_B=0$				
Voltage						
BC174			65			V
BC171			45			V
BC172			25			V
Emitter Base Breakdown	$BV_{EBO}$	$I_{E}=100\mu A, I_{C}=0$				
Voltage						
ALL			6			V
Collector Cut off Current	I <sub>CES</sub>					
BC174		$V_{CE} = 70V, V_{BE} = 0$			15	nA
BC171		$V_{CE} = 50V, V_{BE} = 0$			15	nA
BC172		$V_{CE} = 35V, V_{BE} = 0$			15	nA
		$V_{CE} = 30V, V_{BE} = 0,$			4	μΑ
		Ta= 125ºC				

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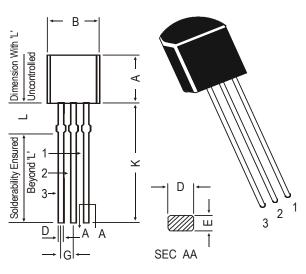
TO-92 **Plastic Package** 

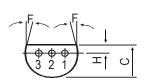
DESCRIPTION	SYMBOL TEST CONDITION					
			MIN	TYP	MAX	UNIT
DC Current Gain	h <sub>FE</sub>	$V_{CE}=5V,I_{C}=10\mu A$				
BC171A, 2A, 4A				90		
BC171B, 2B, 4B				150		
BC172C				270		
		$V_{CE}=5V,I_{C}=2mA$				
BC174			120		450	
BC171			120		800	
BC172			120		800	
BC171A, 2A, 4A			120		220	
BC171B, 2B, 4B			180		460	
BC172C			380		800	
		V <sub>CE</sub> =5V,I <sub>C</sub> =100mA				
BC171A, 2A, 4A		<u> </u>		120		
BC171B, 2B, 4B				180		
BC171C				300		
BC172C				300		
Page Emitter Saturation Valtage	V	I <sub>C</sub> =10mA,I <sub>B</sub> =0.5mA		0.7		V
Base Emitter Saturation Voltage	V <sub>BE(sat)</sub>	IC= IUIIIA,IB=U.SIIIA		0.7		V
Collector Emitter Seturation	\/	1 10m			0.05	V
Collector Emitter Saturation	V <sub>CE (sat )</sub>	I <sub>C</sub> =10mA,I <sub>B</sub> =0.5mA			0.25	
Voltage		I <sub>C</sub> =100mA,I <sub>B</sub> =5mA			0.60	V
Base Emitter on Voltage	V <sub>BE (on)</sub>	$I_C=2mA$ , $V_{CE}=5V$	0.55		0.70	V
DYNAMIC CHARACTERISTICS						
STINAINIO ONARAOTERIOTIOO						
Transition Frequency	f <sub>T</sub>	I <sub>C</sub> =10mA, V <sub>CE</sub> =5V				
BC171		f=100MHz	150			MHz
BC172			150			
BC174			150			
Output Capacitance	C <sub>ob</sub>	I <sub>E</sub> =0, V <sub>CB</sub> =10V			4.50	pF
		f=1MHz				
Input Capacitance	$C_{ib}$	Ic=0, V <sub>EB</sub> =0.5V		10		рF
		f=1MHz				
Ome all Cinne al Commont Code	16 1	\/				
Small Signal Current Gain	h <sub>fe</sub>	$V_{CE} = 5V, I_{C} = 2mA$	105		000	
BC171, 2, 4		f=1KH <sub>Z</sub>	125		900	
BC171A, 2A, 4A,			125		260	
BC171B, 2B, 4B			240		500	
BC172C			450		900	
Noise Figure	NF	$V_{CE} = 5V, I_{C} = 0.2mA$			10	dB
BC171		$R_S=2K\Omega, f=1KH_{Z_1}f=200Hz$			10	
BC172				-	10	
BC174						

# **TO-92 Plastic Package**

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## TO-92 Transistors on Tape and Ammo Pack



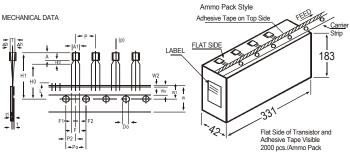


#### PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

DIM	MIN.	MAX.					
Α	4.32	5.33					
В	4.45	5.20					
С	3.18	4.19					
D	0.41	0.55					
Ε	0.35	0.50					
F	5 DEG						
G	1.14	1.40					
Н	1.14	1.53					
K	12.70	_					
L	1.982	2.082					

All diminsions in mm.



#### All dimensions in mm unless specified otherwise

ITEM	0		SPECIF	ICATIO	N	DELLA DICO
ITEM	SYMBOL	MIN.	NOM.	MAX.	TOL.	REMARKS
BODY WIDTH BODY HEIGHT BODY THICKNESS PITCH OF COMPONENT	A1 A T P	4.0 4.8 3.9	12.7	4.8 5.2 4.2	±1	
FEED HOLE CENTRE TO	Po		12.7		±0.3	CUMULATIVE PITCH ERROR 1.0 mm/20 PITCH
COMPONENT CENTRE	P2		6.35		±0.4	TO BE MEASURED AT BOTTOM OF CLINCH
DISTANCE BETWEEN OUTER LEADS COMPONENT ALIGNMENT	F ∆h		5.08 0	1	+0.6 -0.2	AT TOP OF BODY
TAPE WIDTH HOLD-DOWN TAPE WIDTH HOLE POSITION	W Wo W1		18 6 9	•	±0.5 ±0.2 +0.7 -0.5	AT TOP OF BODT
HOLD-DOWN TAPE POSITION LEAD WIRE CLINCH HEIGHT COMPONENT HEIGHT LENGTH OF SNIPPED LEADS	W2 Ho H1 L		0.5 16	23.25 11.0	±0.2 ±0.5	
FEED HOLE DIAMETER TOTAL TAPE THICKNESS LEAD - TO - LEAD DISTANCEF1,	Do t F2		4 2.54	1.2	±0.2 +0.4 -0.1	t1 0.3 - 0.6
CLINCH HEIGHT PULL - OUT FORCE	H2 (P)	6N		3		

- NOTES

  1. MAXIMUM ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.

  2. MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20 HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO EXPOSURE OF ADHESIVE.

- A. NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.
   A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.
   SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

# **Packing Detail**

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size Qty		Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

**Notes** 

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#### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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